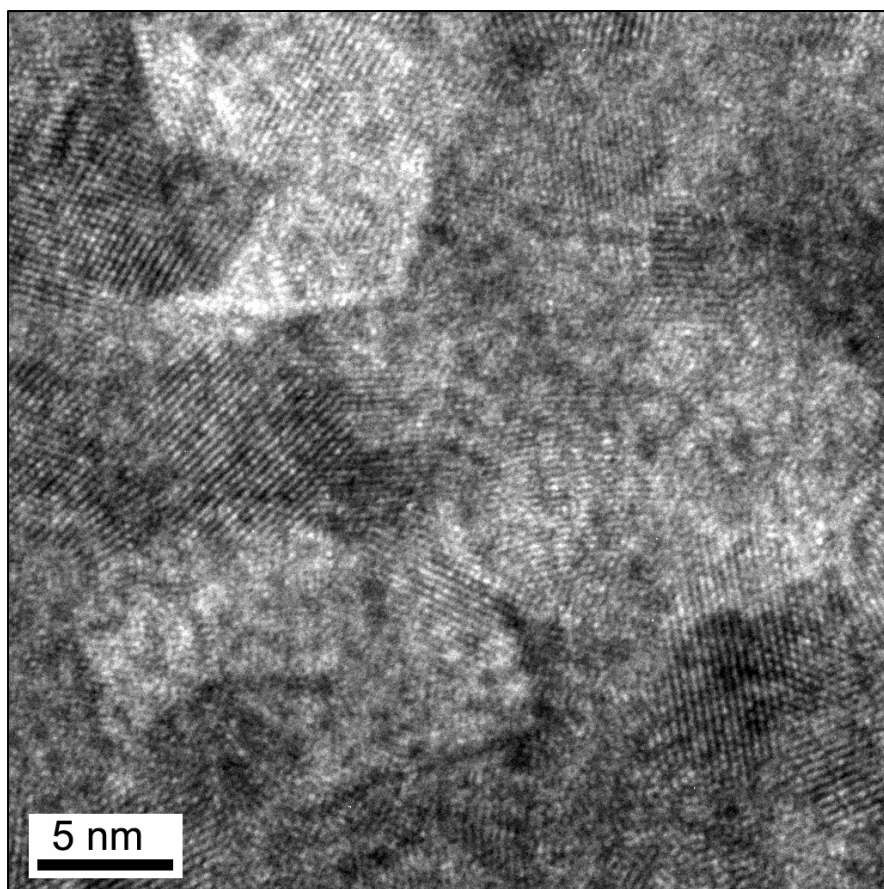


Phase reversibility in $(\text{Pb},\text{La})(\text{Zr},\text{Ti})\text{O}_3$ thin-film ferroelectrics studied by transmission electron microscopy



Chad M. Parish
Geoff L. Brenneka
Bruce A. Tuttle
Mark A. Rodriguez
Luke N. Brewer

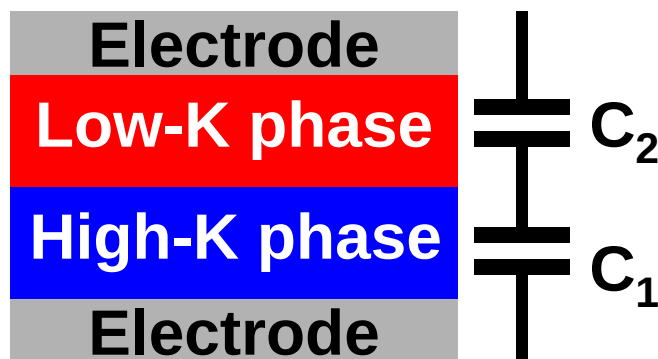
Thin-film P(L)ZT ferroelectrics are important for capacitor applications

$\text{Pb}(\text{Zr},\text{Ti})\text{O}_3$ and $(\text{Pb},\text{La})(\text{Zr},\text{Ti})\text{O}_3$ are high-dielectric-constant (K) ferroelectrics that can be formed into multilayer thin films

→ Referred to as PZT and PLZT

Multiple phases can form during processing – these act as series capacitors

→ Loss of overall capacitance of device



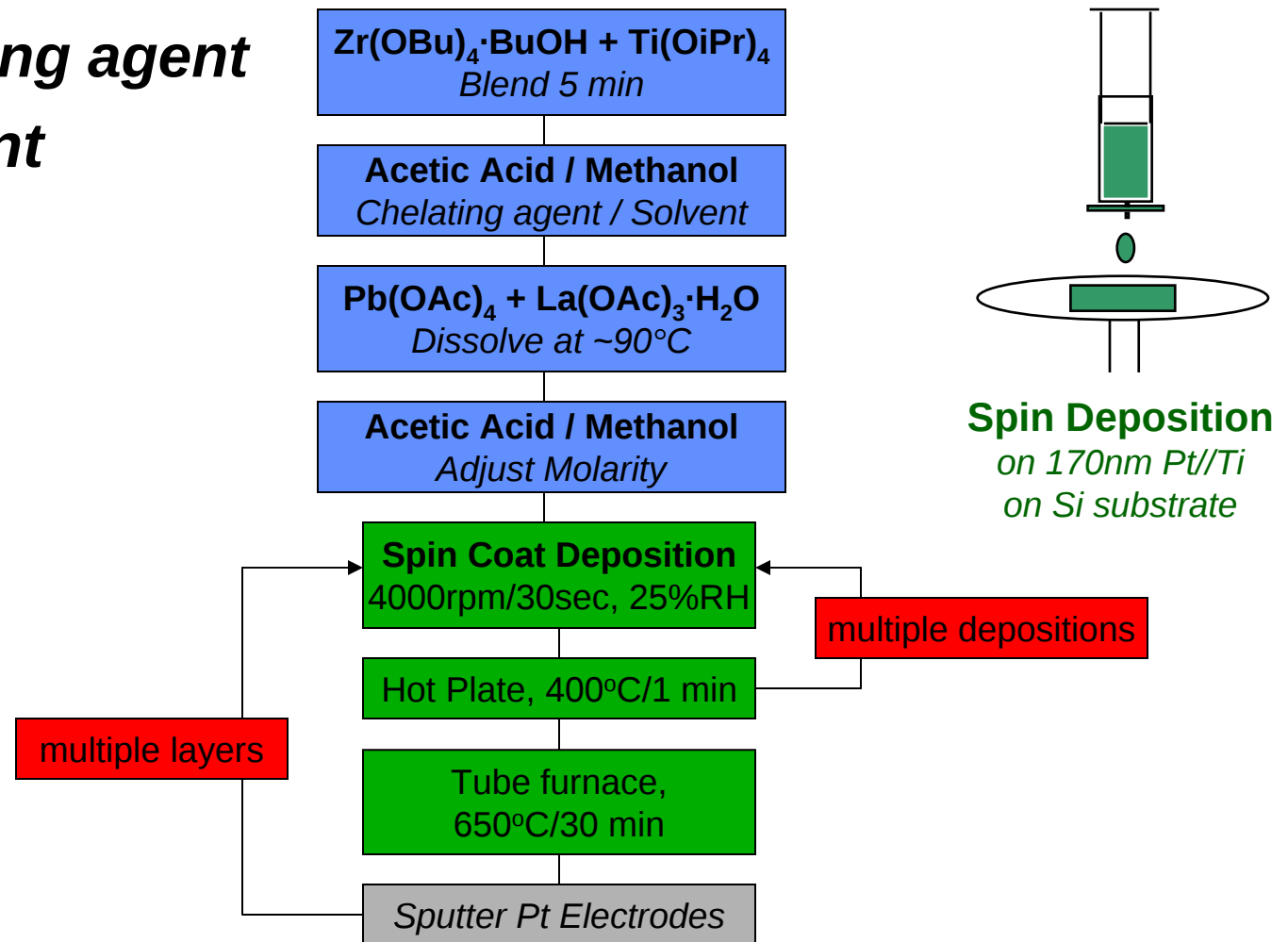
$$C_{\text{TOTAL}} = \frac{1}{\frac{1}{C_1} + \frac{1}{C_2}}$$

Lowest capacitance value dominates device performance!

We used chemical solution deposition to make P(L)ZT thin films

HOAc = *chelating agent*

MeOH = *solvent*



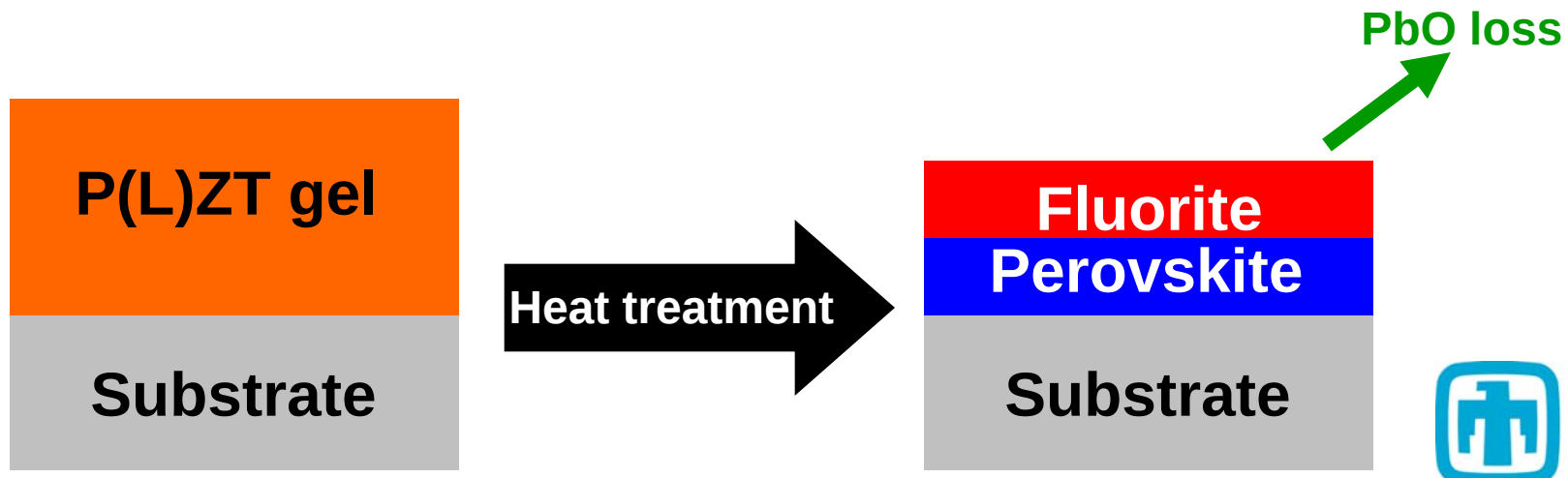
PbO volatility can result in poor film quality

Only the perovskite phase of P(L)ZT has a high dielectric constant K

Perovskite is intolerant of Pb non-stoichiometry

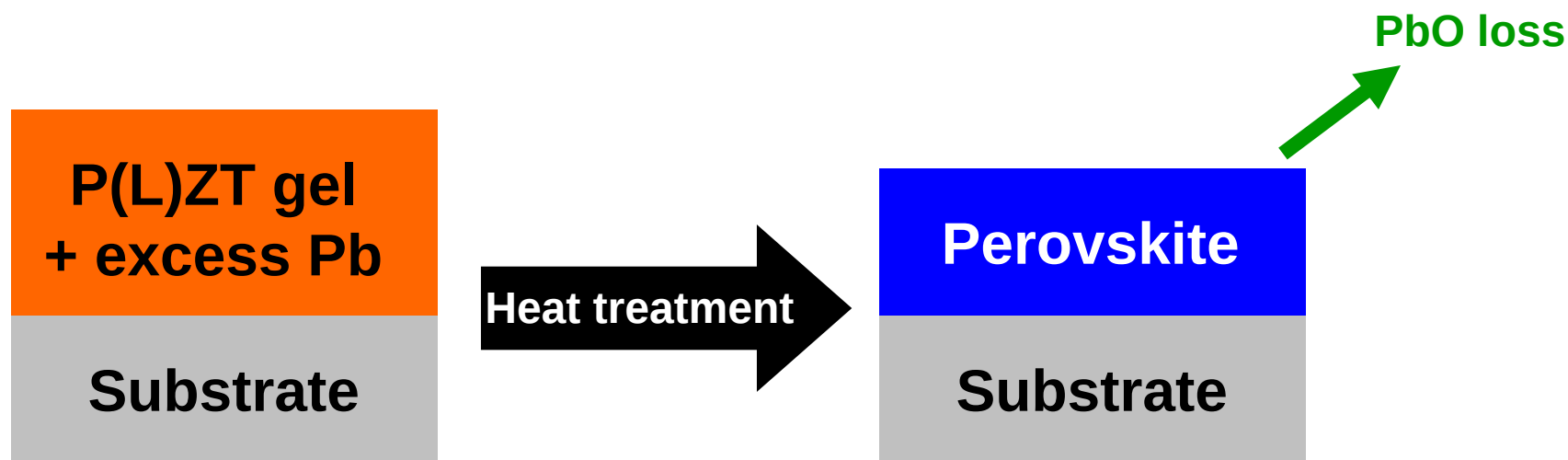
When Pb-deficient, fluorite phase forms, with poor dielectric properties

PbO is volatile $\rightarrow$ lost during processing
 $\rightarrow$ mixed-phase films with low K -values



Excess Pb avoids fluorite formation, but has detrimental effects

Typically, 10-20% excess Pb is added to the precursor

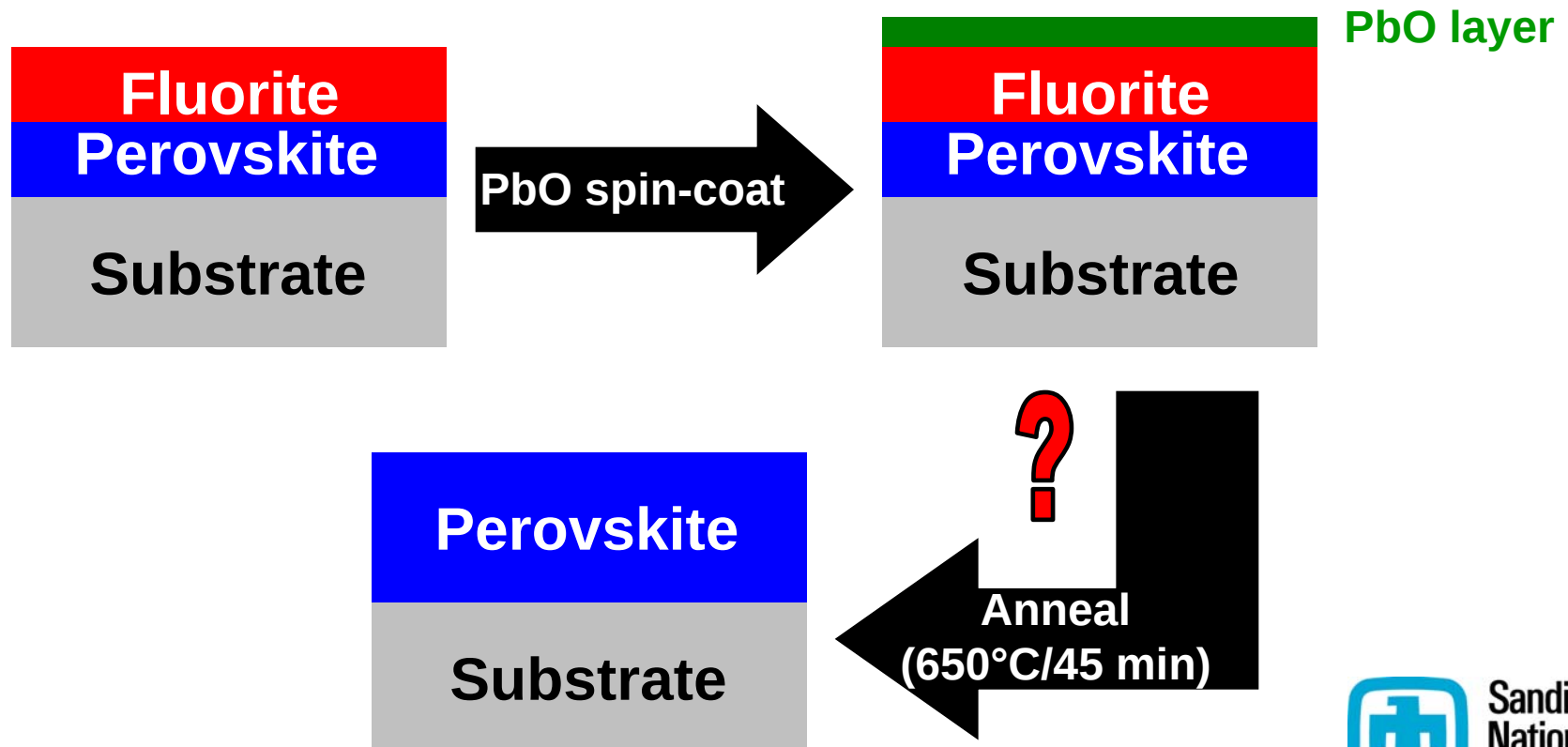


Thinner films require more Pb excess, which interacts with the electrode and substrate

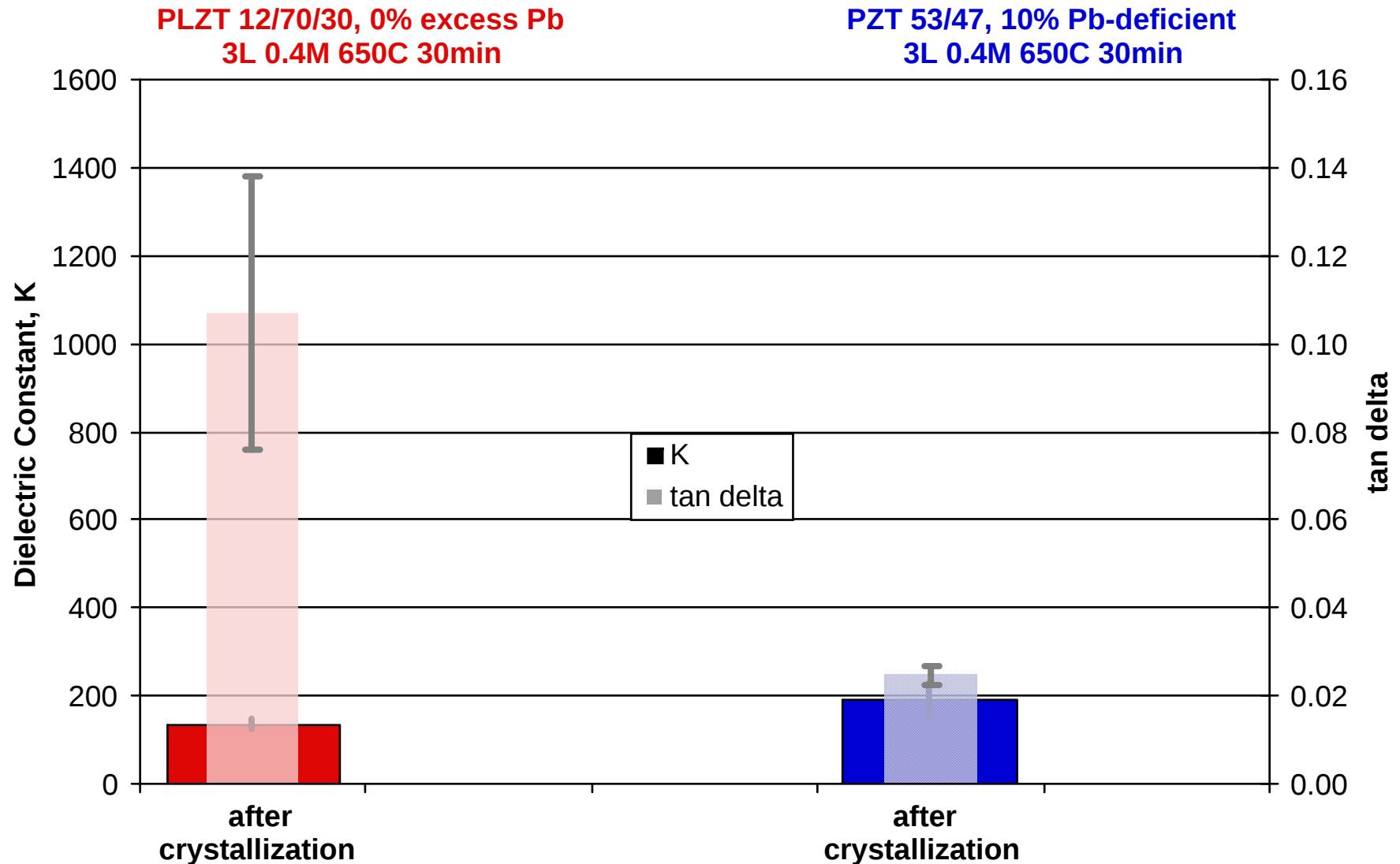
Can we produce single-phase perovskite P(L)ZT without excess Pb?

Will annealing crystallized films under a PbO solution restore the desired phase?

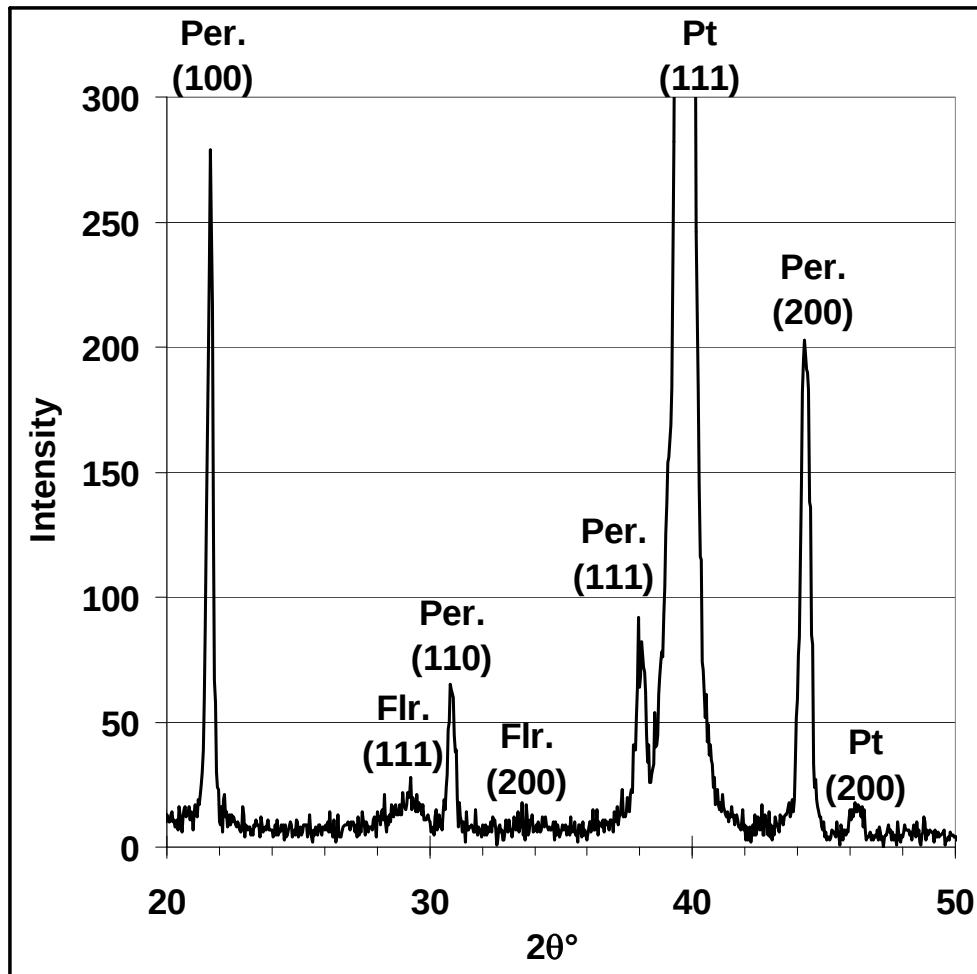
Hypothesis: If we coat mixed-phase perovskite + fluoride films with PbO solution and anneal, the fluoride will convert to the desired perovskite phase



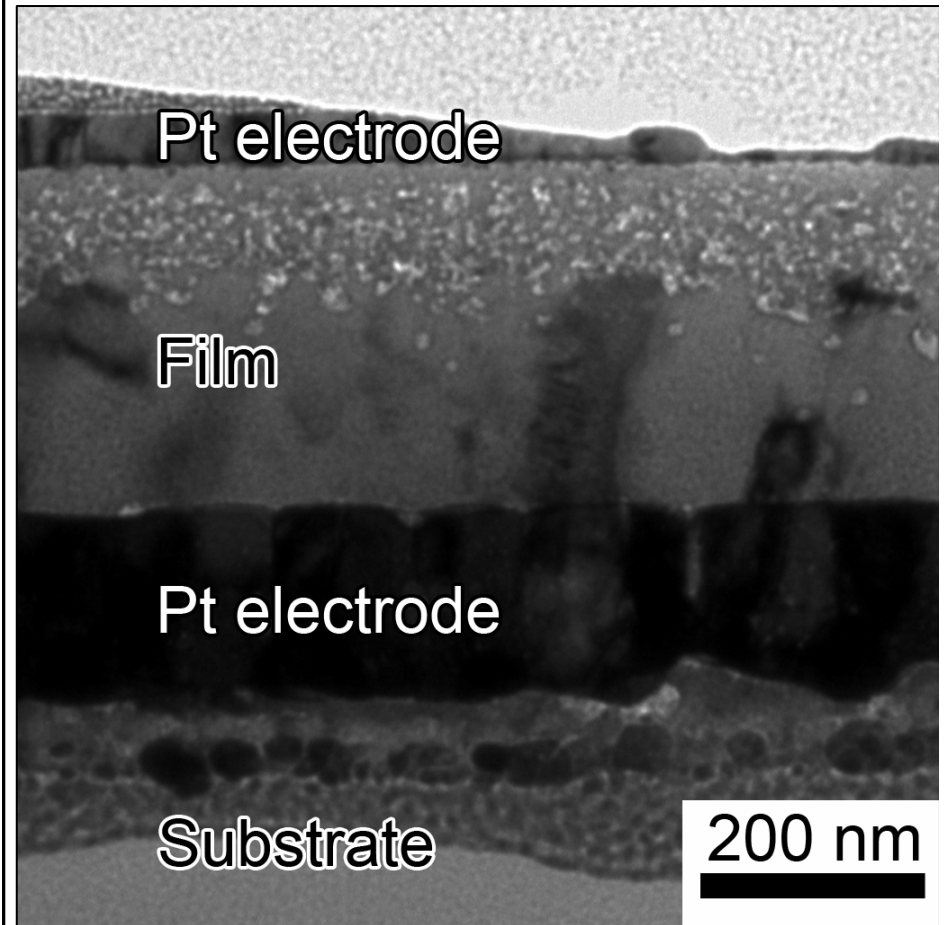
As-crystallized films show poor dielectric properties (K=100~200)



As-crystallized films show mixed-phase structure in XRD and TEM

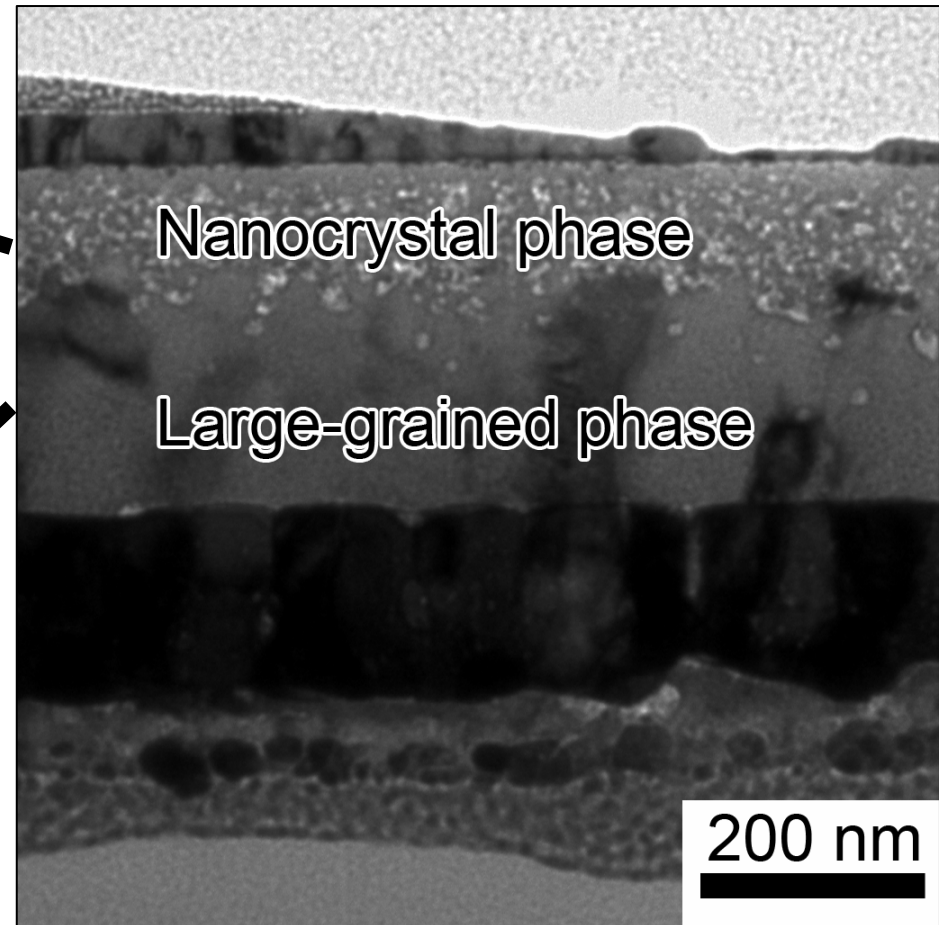
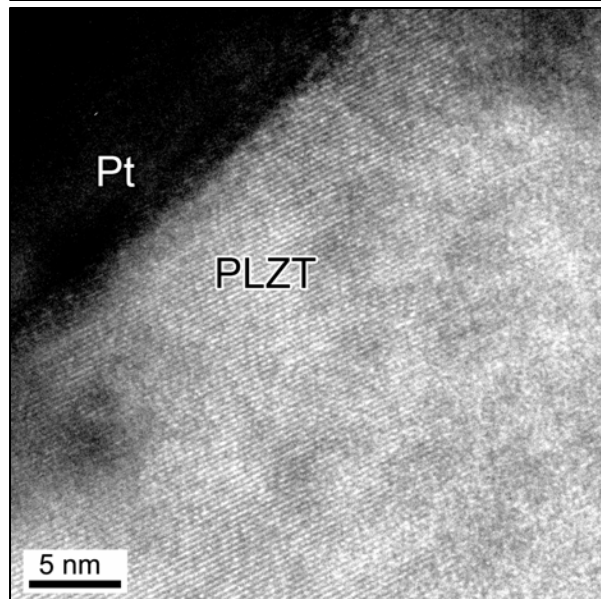
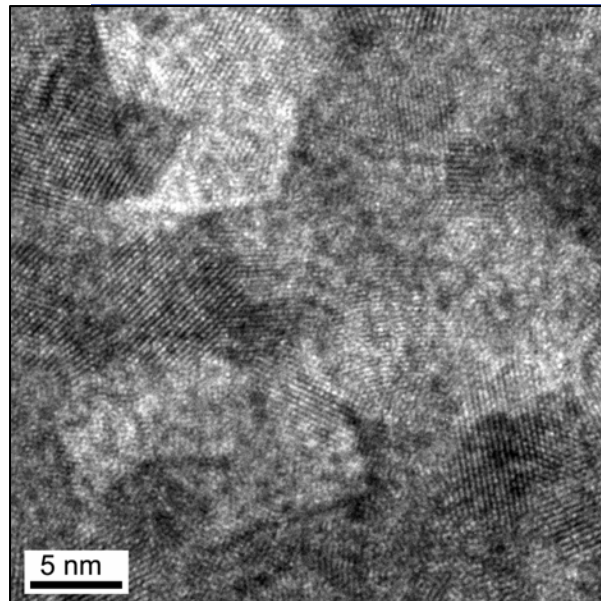


Per. = Perovskite
Flr. = Fluorite



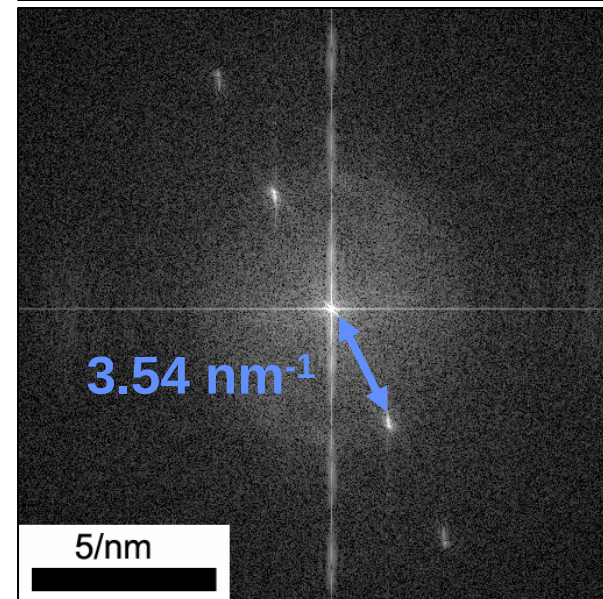
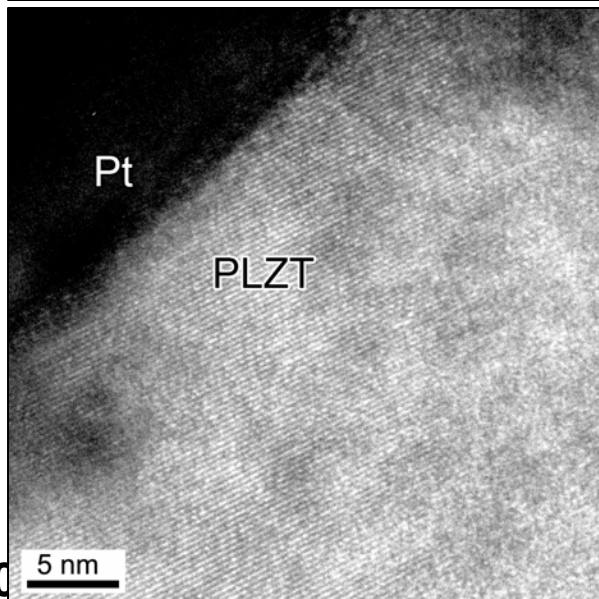
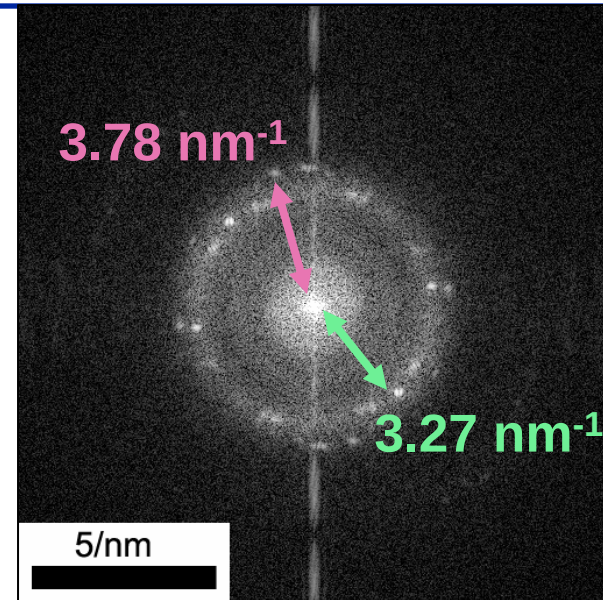
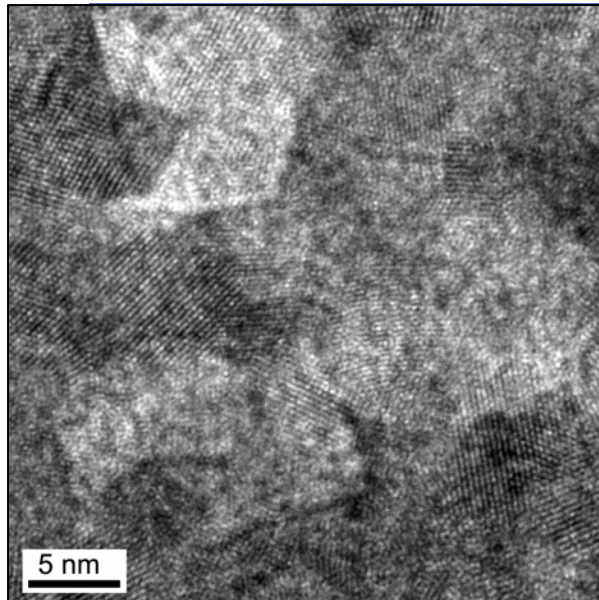
PLZT 12/70/30

High-resolution TEM shows crystal structure

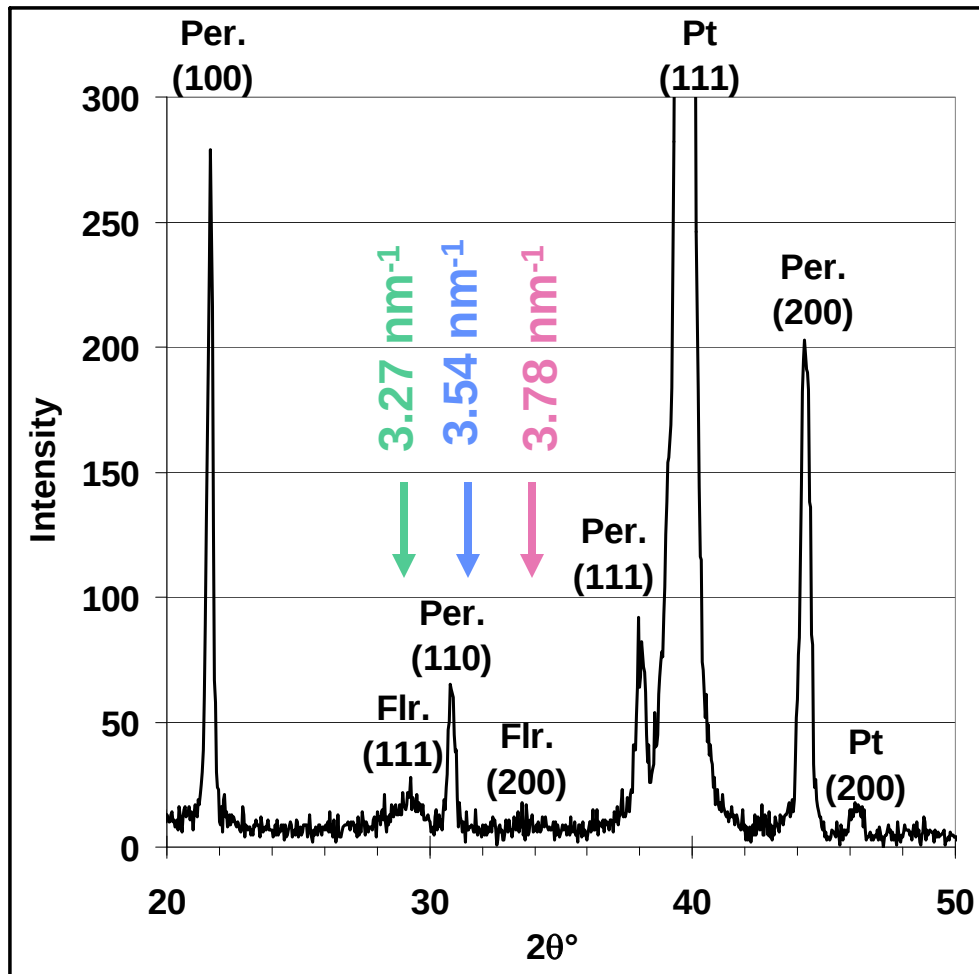


PLZT 12/70/30

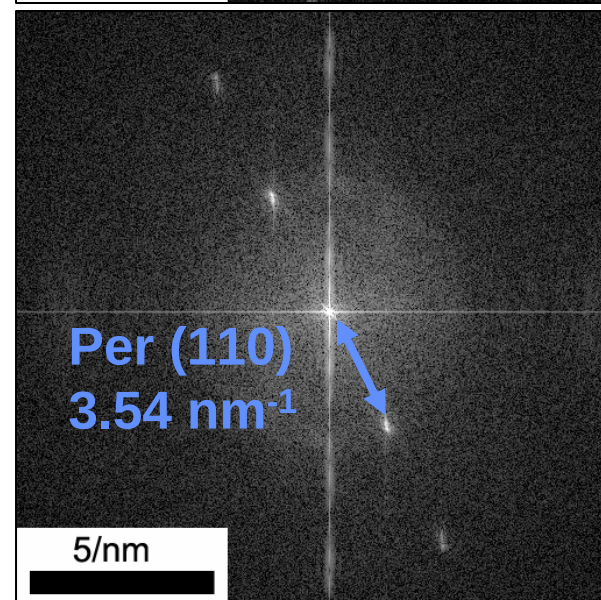
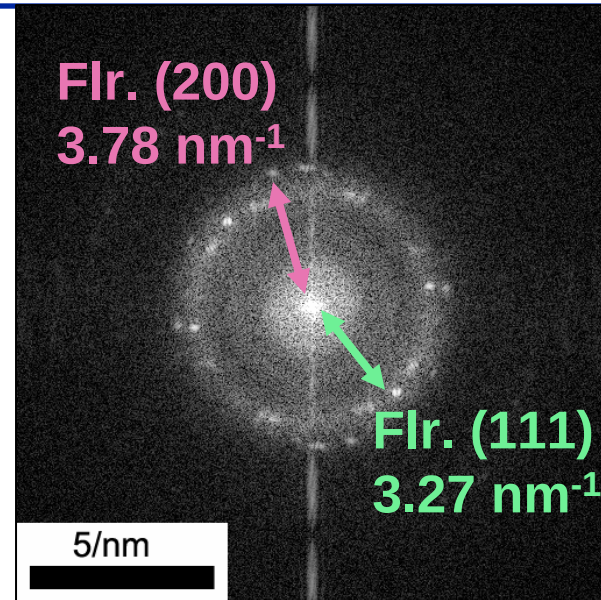
Fourier transforms allow lattice spacings to be determined



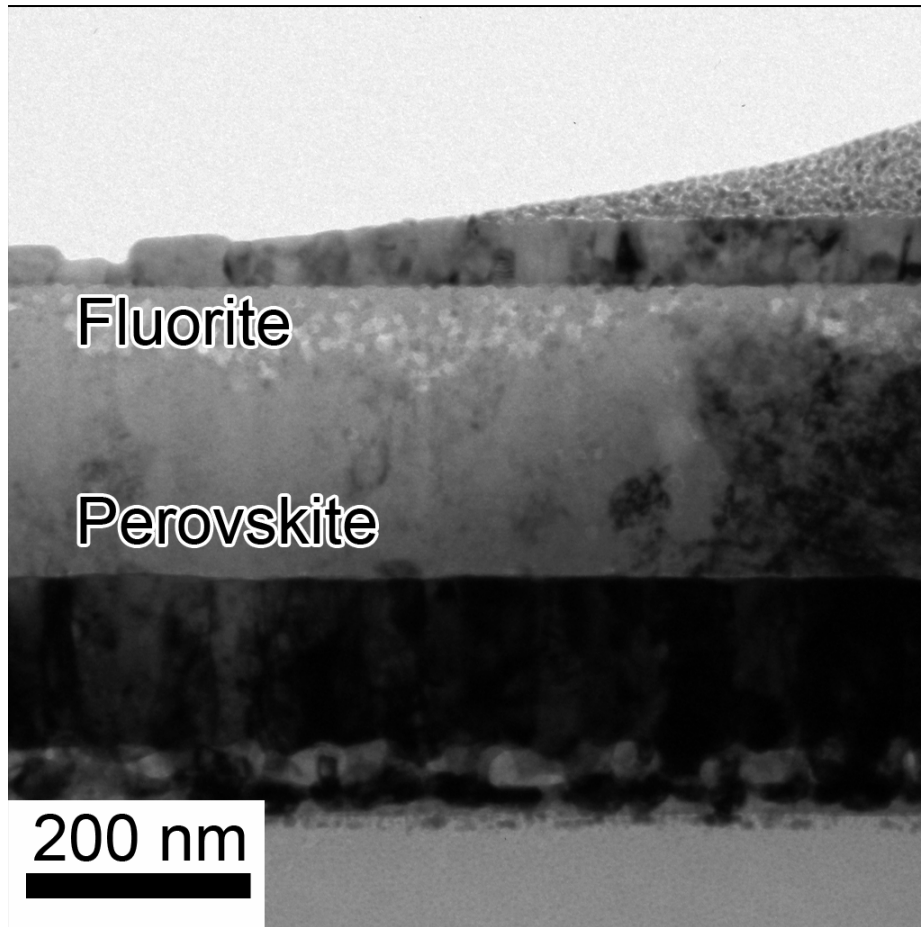
TEM lattice spacings match XRD data



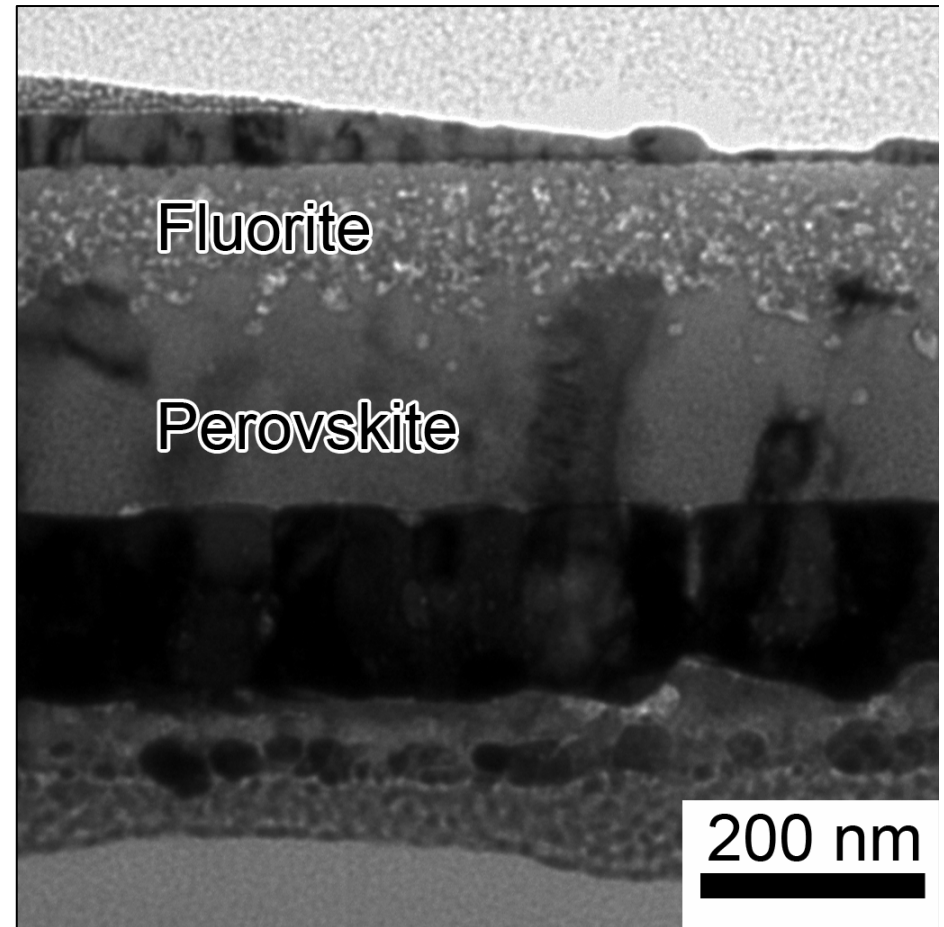
Per. = Perovskite
Flr. = Fluorite



As-crystallized samples suffer from surface fluorite formation



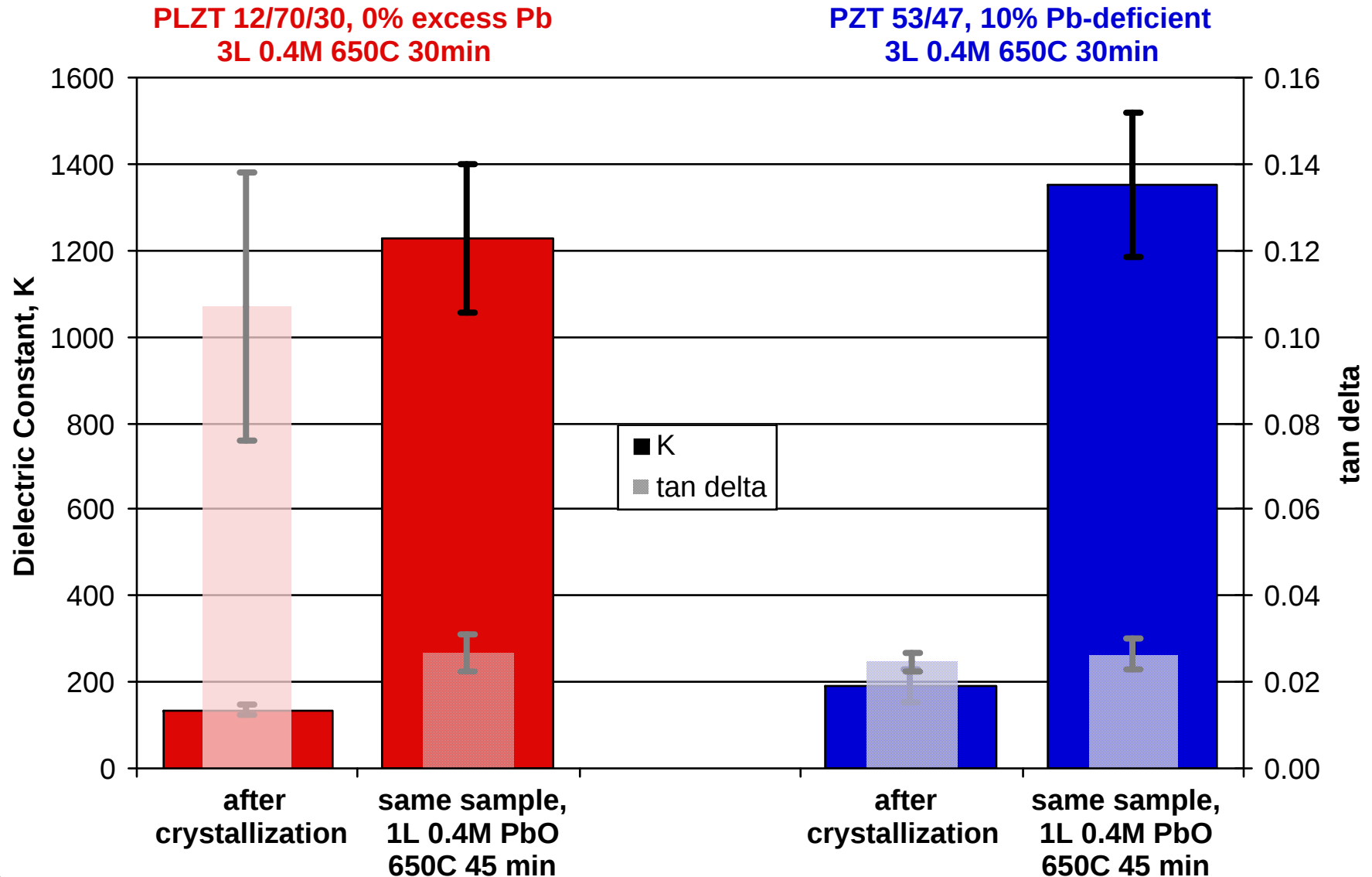
PZT 53/47



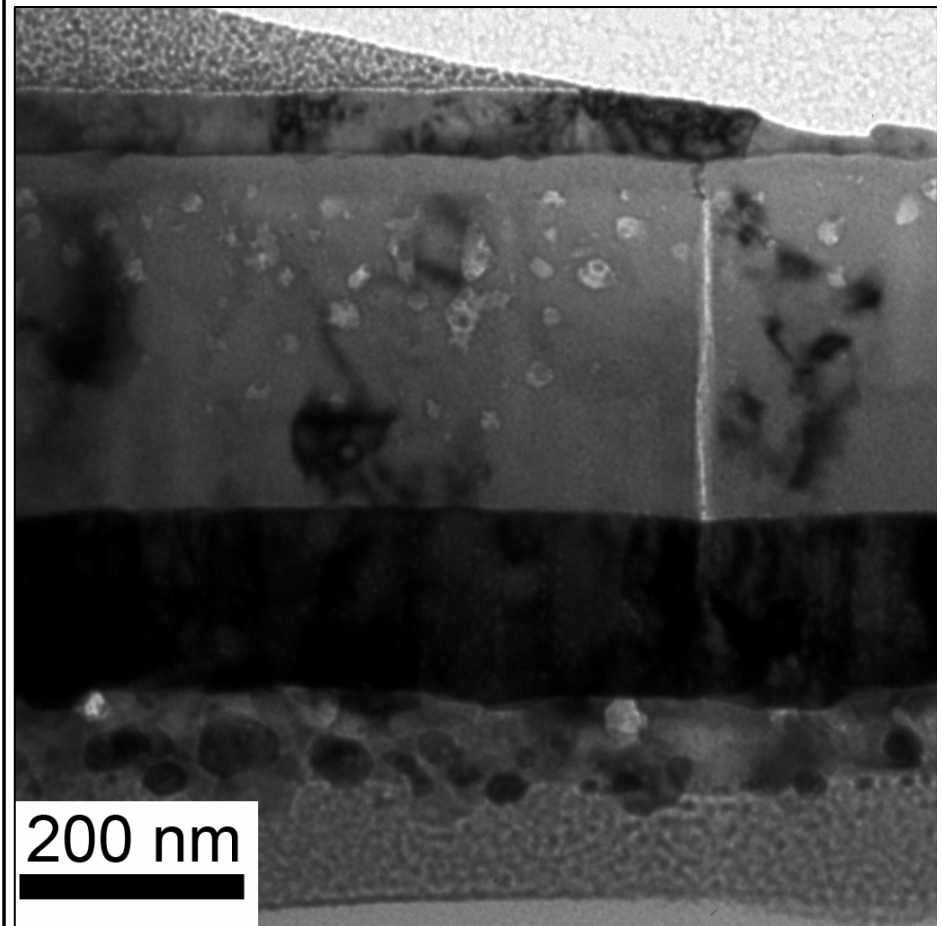
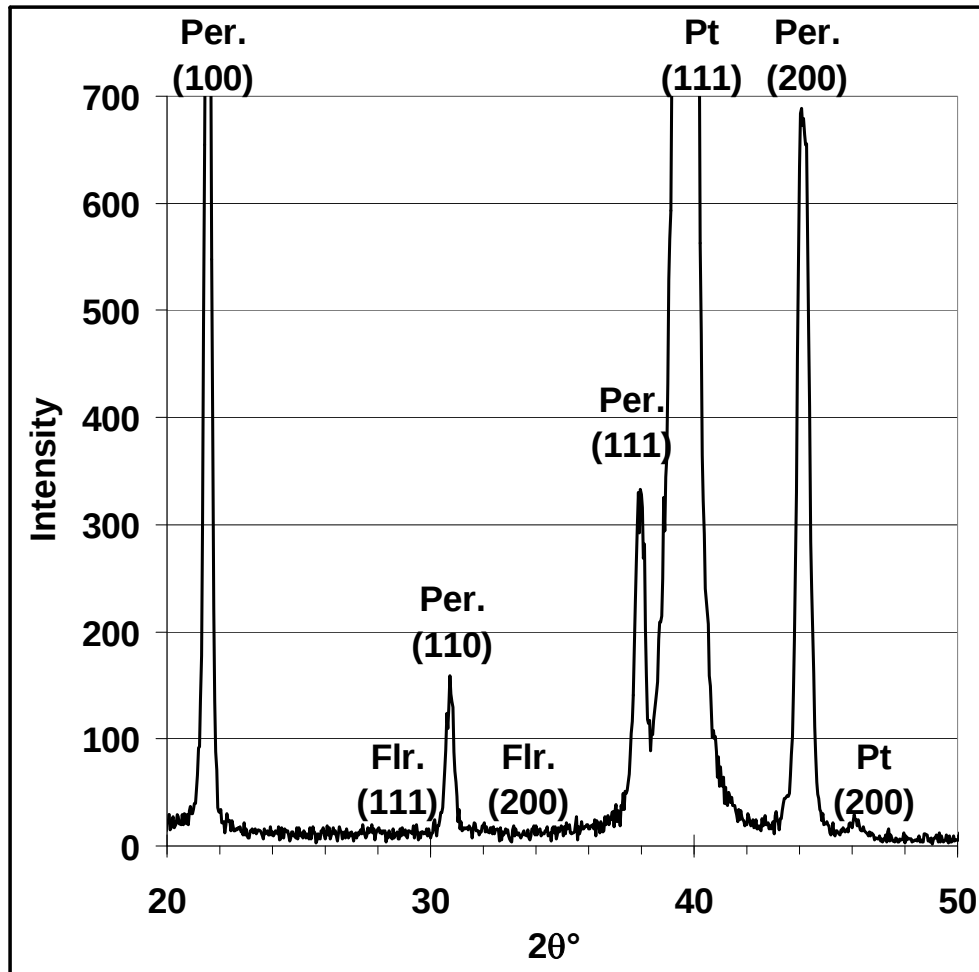
PLZT 12/70/30

→ Causes poor dielectric
properties ($K=100\sim200$)

Overcoated + annealed films show improvement in dielectric properties ($K > 1000$)



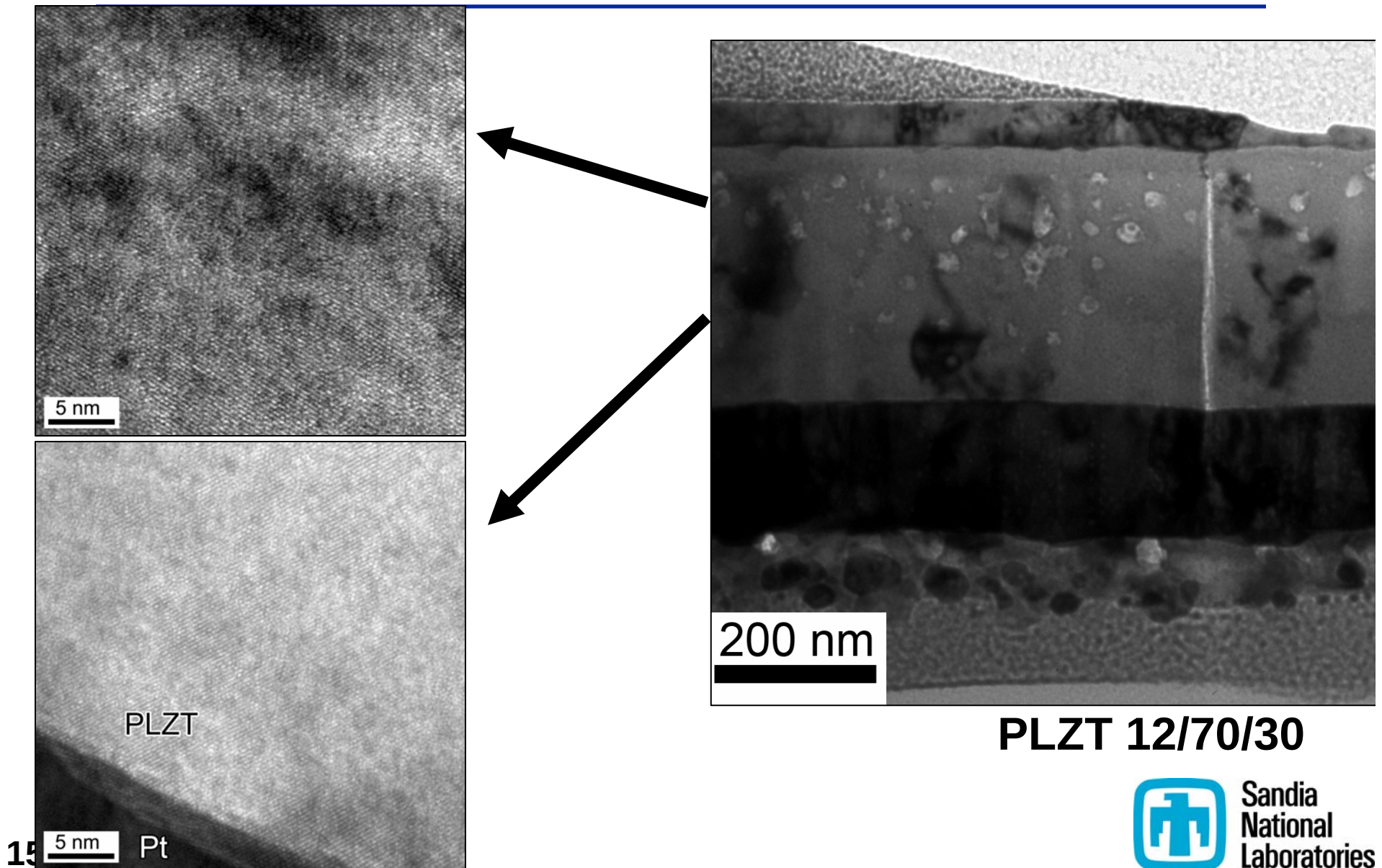
After overcoating + annealing, XRD and TEM show a single-phase material



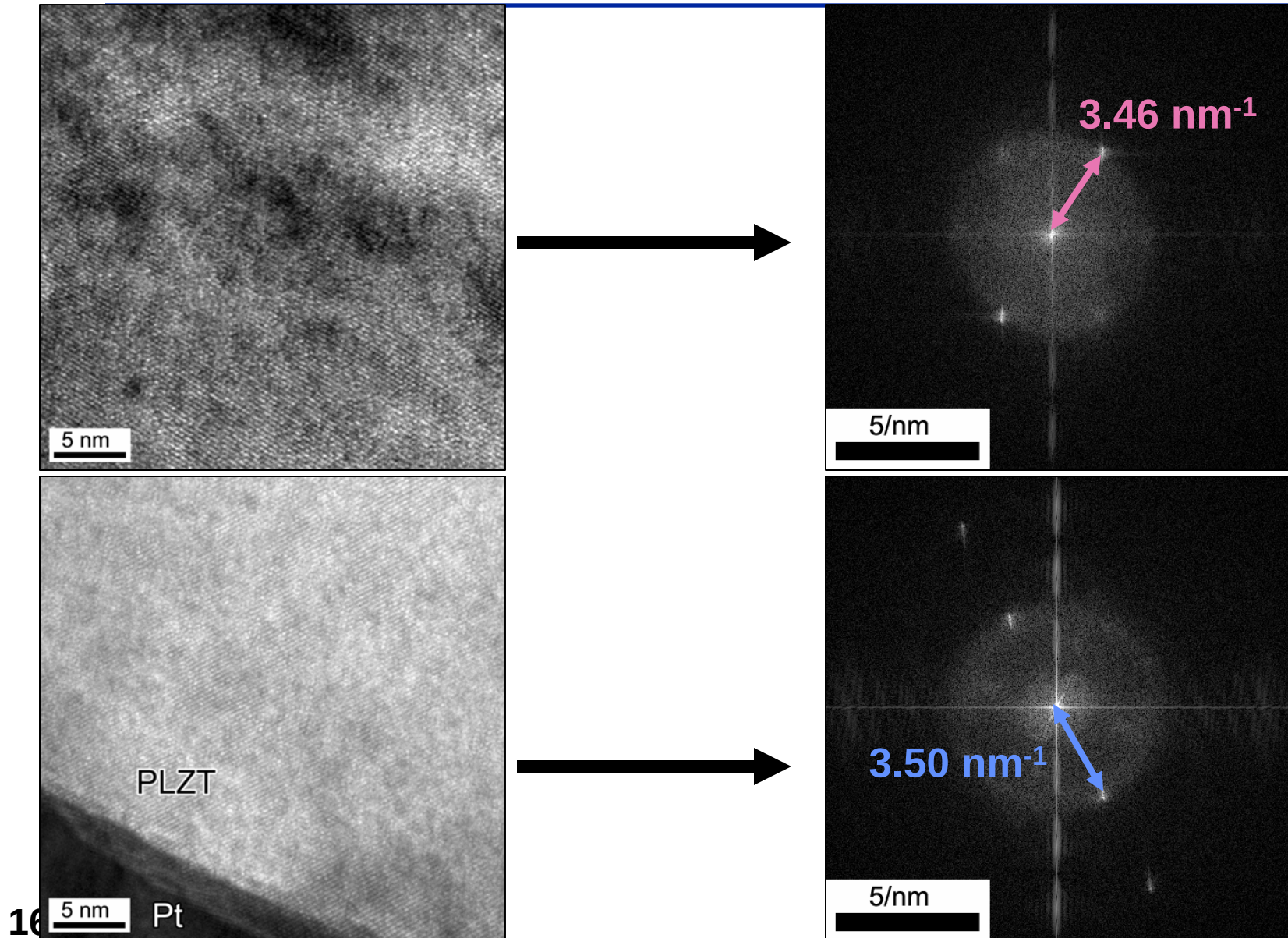
PLZT 12/70/30

Per. = Perovskite
Flr. = Fluorite

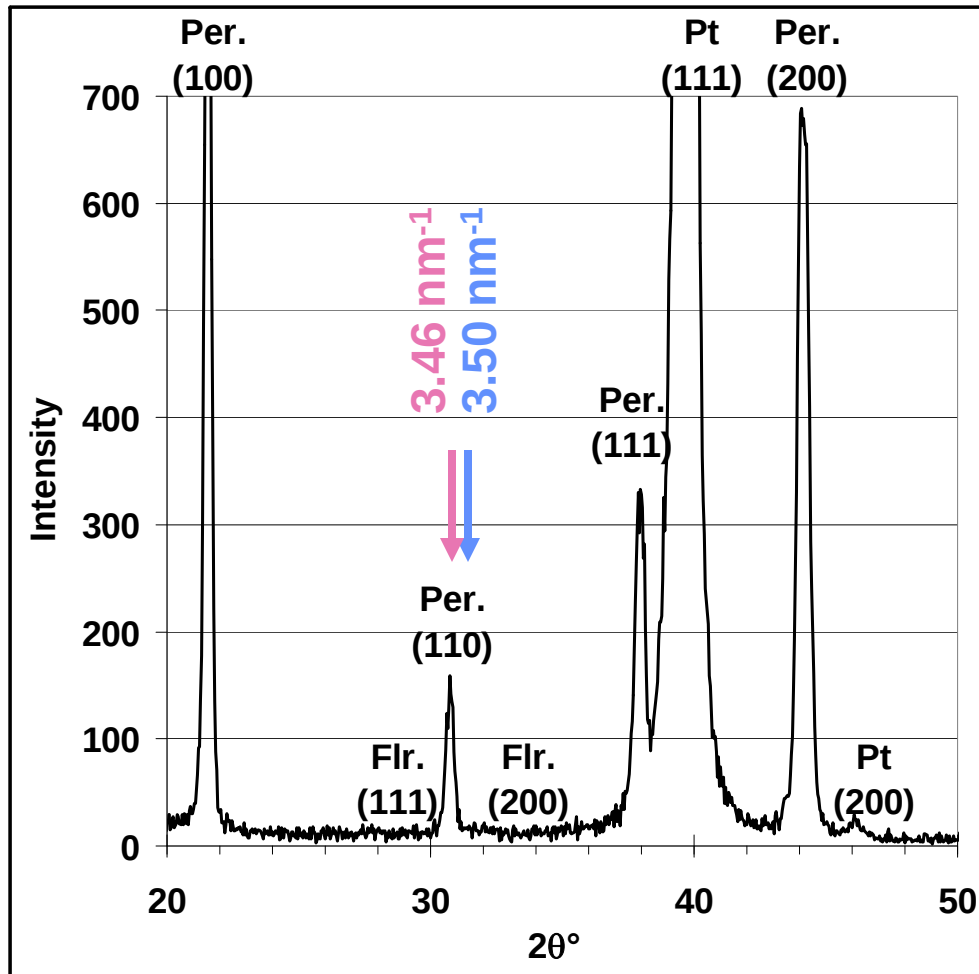
High-resolution TEM shows crystal structure



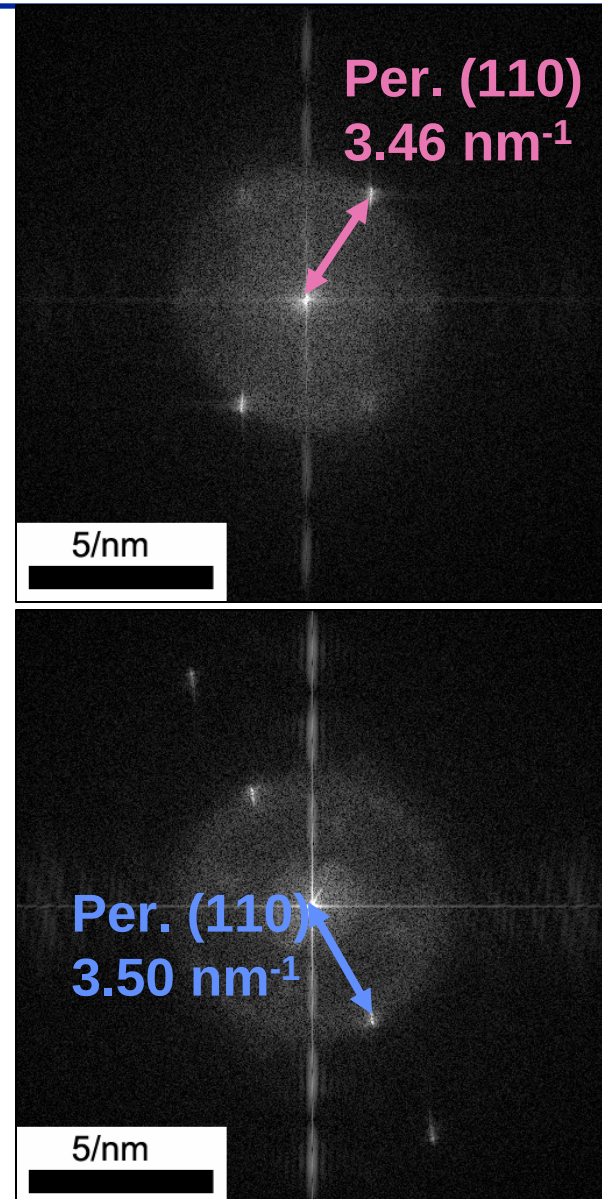
Fourier transforms allow lattice spacings to be determined



TEM lattice spacings match XRD data

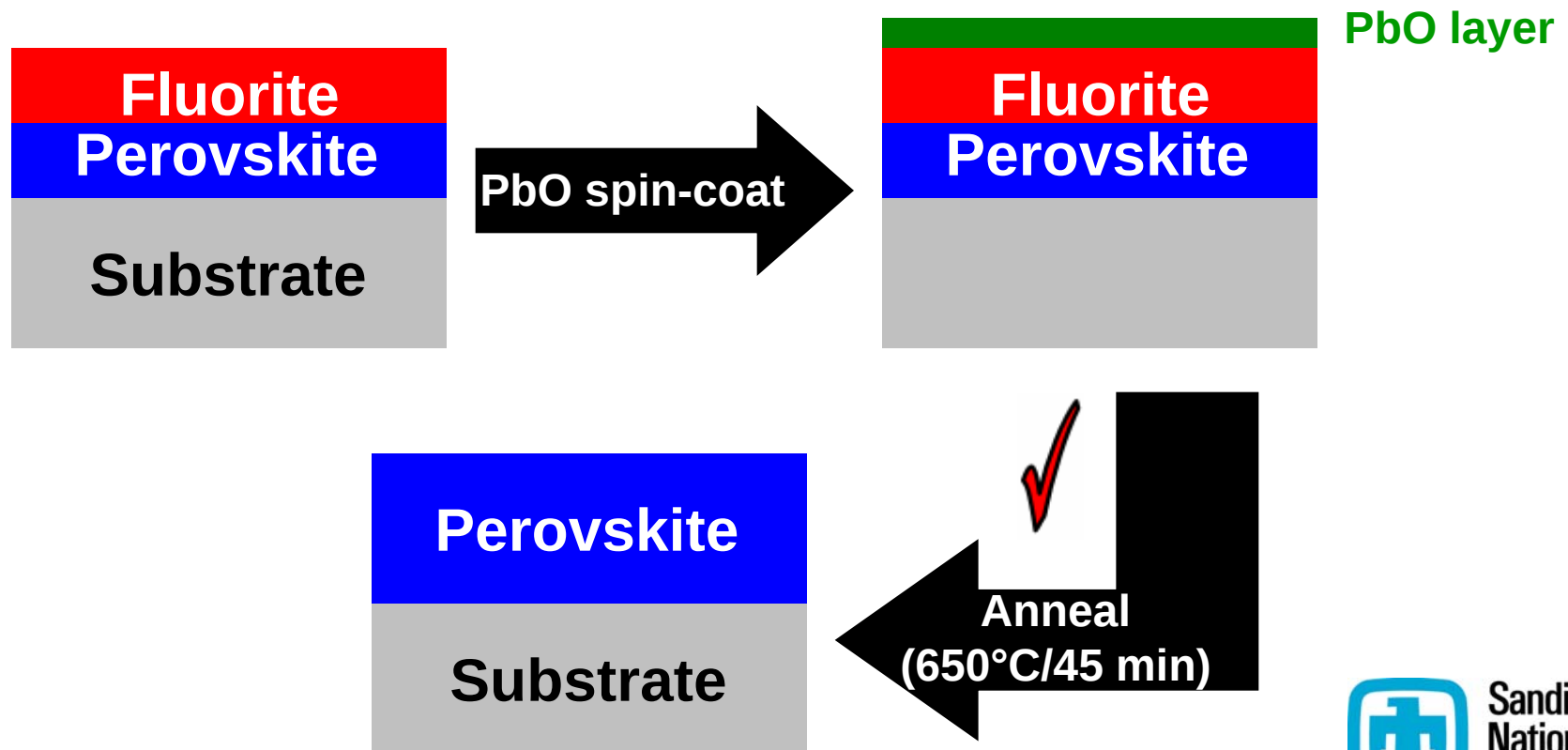


Per. = Perovskite
Flr. = Fluorite



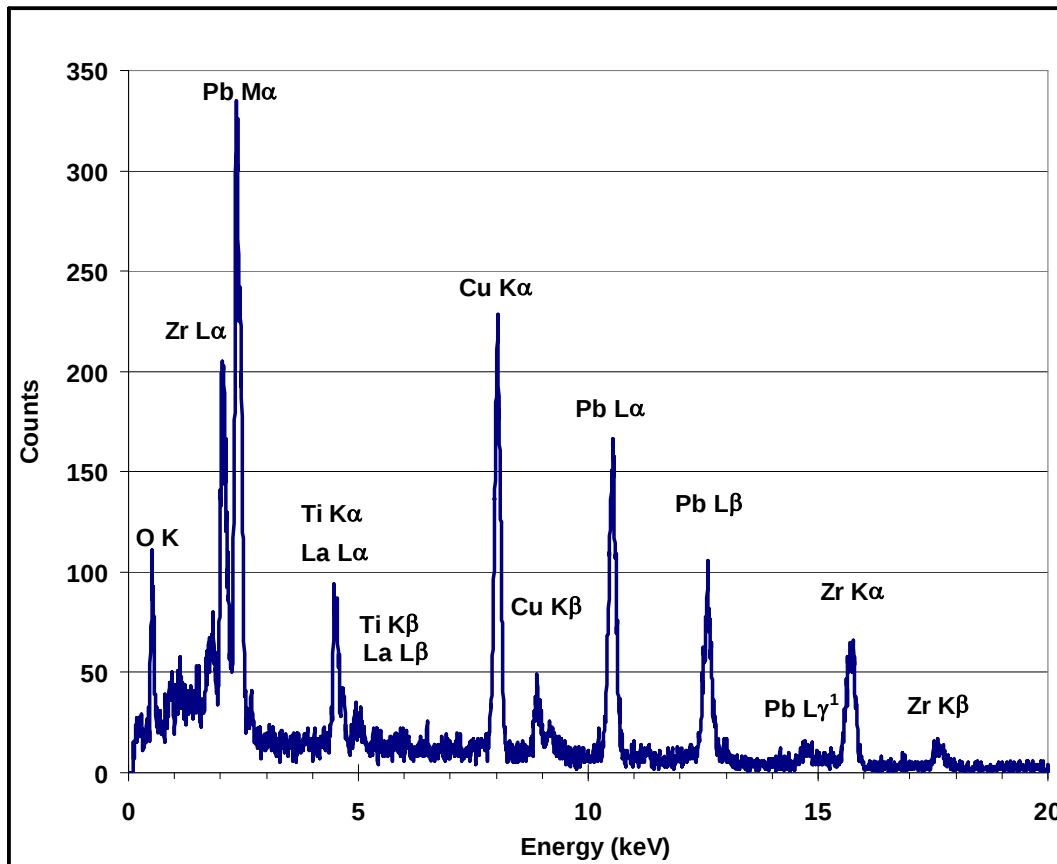
We have confirmed our hypothesis

Hypothesis: *If we coat mixed-phase perovskite + fluoride films with PbO solution and anneal, the fluoride will convert to the desired perovskite phase*

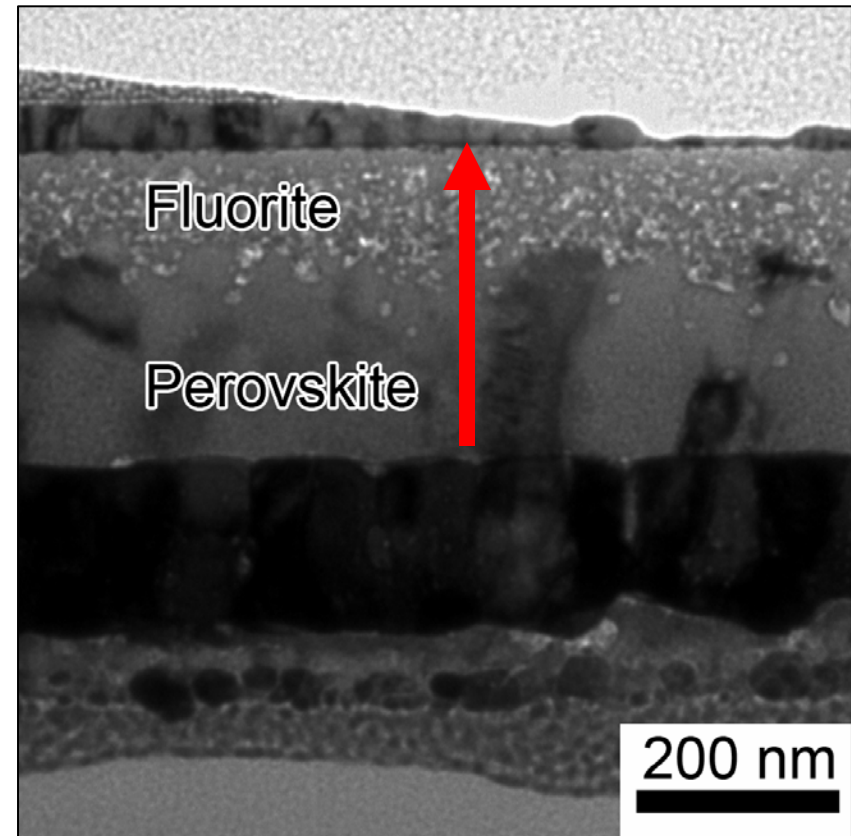


Can we confirm our proposed mechanism of Pb-replenishment using EDS?

Typical point spectrum



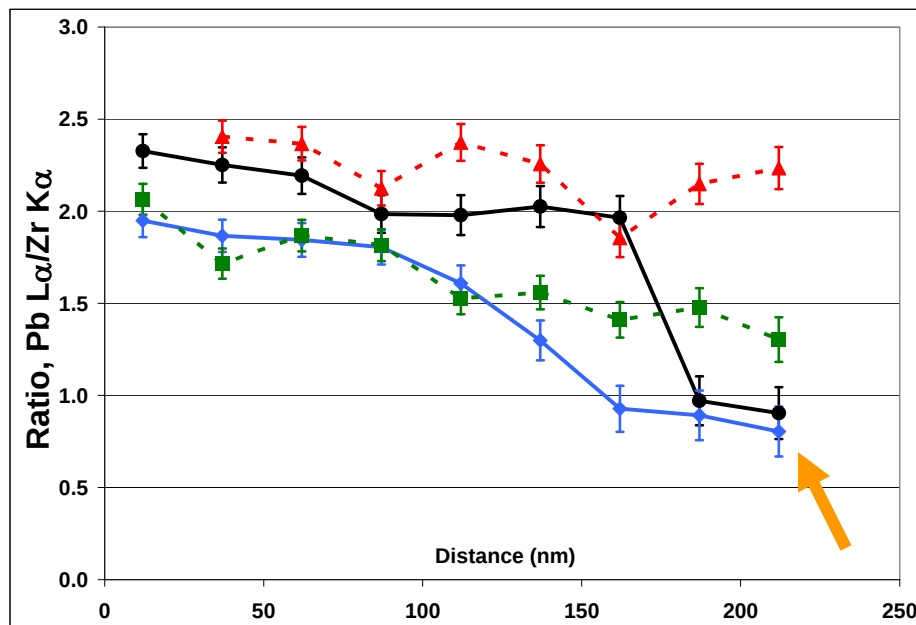
EDS linescan direction



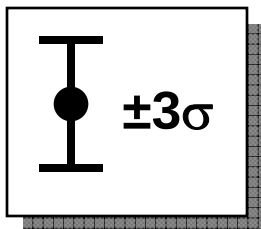
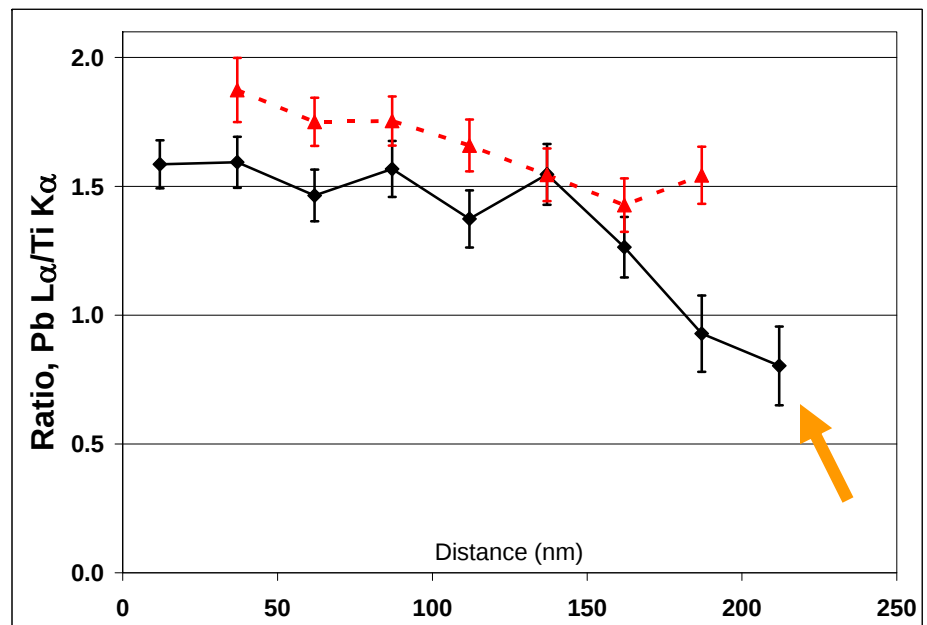
PLZT 12/70/30

In the two-phase samples, the Pb content drops significantly near the surface (fluorite)

Pb to Zr ratios



Pb to Ti ratios



- PZT 53/47, single phase
- PZT 53/47, two phase
- PLZT 12/70/30, single phase
- PLZT 12/70/30, two phase

We have shown that Pb-deficient P(L)ZT can be converted to perovskite after annealing

This may allow us to use less Pb-excesses to minimize substrate interactions

We have confirmed this result with electrical measurements, XRD, and TEM

We next hope to perform quantitative TEM-EDS analyses to help optimize the annealing parameters